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STMicroelectronics STPS30L30DJF-TR

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STPS30L30DJF

High efficiency power Schottky diode

Datasheet - production data

Features

- Low forward voltage drop
- Very small conduction losses
- Negligible switching losses
- Avalanche rated
- Extremely fast switching
- Low thermal resistance
- 1 mm package thickness
- ECOPACK[®]2 compliant component

Description

Single Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in PowerFLAT[™] 5x6, this device is intended for use in low voltage high frequency inverters.

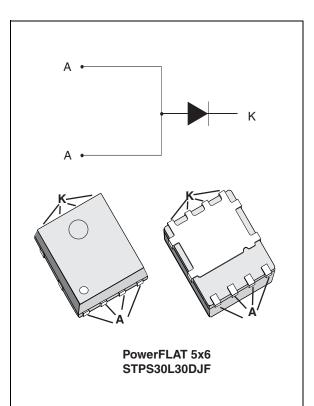


Table 1.Device summary

Symbol	Value
I _{F(AV)}	30 A
V _{RRM}	30 V
T _j (max)	150 °C
V _F (typ)	0.30 V

TM: PowerFLAT is a trademark of STMicroelectronics

March 2012

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Characteristics

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1 Characteristics

Table 2. Absolute ratings (limiting values with anode terminals short-circuited)

Parameter	Value	Unit	
Repetitive peak reverse voltage		30	V
Forward rms current		45	А
Average forward current $\delta = 0.5$ T _c = 110 °C		30	А
Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		250	А
Repetitive peak avalanche power $t_p = 1 \ \mu s, T_j = 25 \ ^{\circ}C$		1300	W
		35	V
Storage temperature range	-65 to + 175	°C	
Maximum operating junction temperatur	150	°C	
	Repetitive peak reverse voltage Forward rms current Average forward current $\delta = 0.5$ Surge non repetitive forward current Repetitive peak avalanche power Maximum repetitive peak avalanche voltage Storage temperature range	Repetitive peak reverse voltageForward rms currentAverage forward current $\delta = 0.5$ $T_c = 110 \ ^{\circ}C$ Surge non repetitive forward current $t_p = 10 \ ^{\circ}ms \ ^$	Repetitive peak reverse voltage30Forward rms current45Average forward current $\delta = 0.5$ $T_c = 110 \ ^{\circ}C$ 30Surge non repetitive forward current $t_p = 10 \ ms \ sinusoidal$ 250Repetitive peak avalanche power $t_p = 1 \ \mu s, \ T_j = 25 \ ^{\circ}C$ 1300Maximum repetitive peak avalanche $t_p < 1 \ \mu s, \ T_j < 150 \ ^{\circ}C, \ 1300$ 35Storage temperature range-65 to + 175

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3.Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2	°C/W

Table 4. Static electrical characteristics (anode terminals short-circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_(1)	R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V _R = 30 V	-	-	0.75	mA
'R'		T _j = 125 °C		-	100	230	mA
V _F ⁽¹⁾	Forward voltage drop	T _j = 25 °C	l _F = 15 A	-	-	0.44	
		T _j = 125 °C	I _F = 15 A	-	0.30	0.35	V
		T _j = 25 °C	I _F = 30 A	-	-	0.51	v
		T _j = 125 °C	I _F = 30 A	-	0.38	0.45	

1. Pulse test: t_p = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation:

 $P = 0.27 \text{ x } I_{F(AV)} + 0.006 \text{ x } {I_{F}}^{2}_{(RMS)}$





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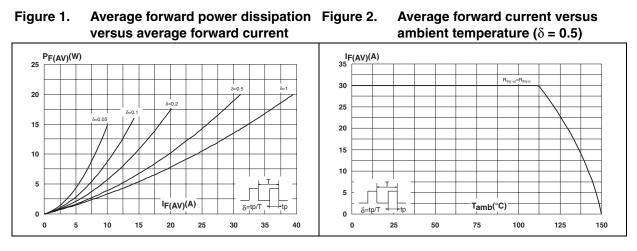


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature

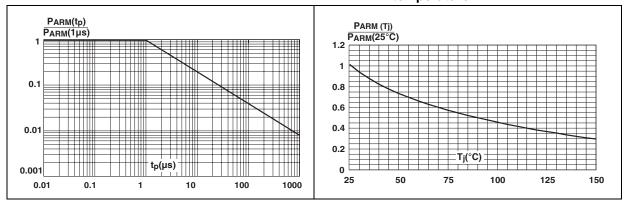
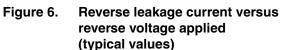
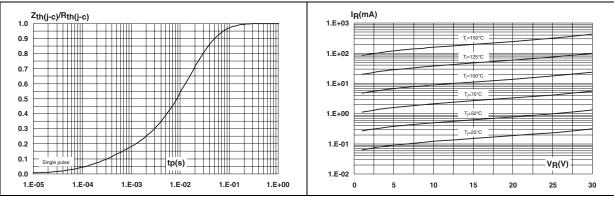


Figure 5. Relative variation of thermal impedance, junction to case, versus pulse duration





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Figure 7. Junction capacitance versus reverse voltage applied (typical values)

Figure 8. Forward voltage drop versus forward current

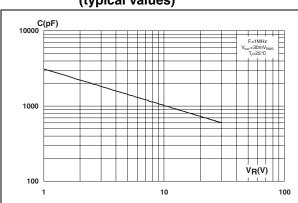


Figure 9. Thermal resistance junction to ambient versus copper surface under each tab

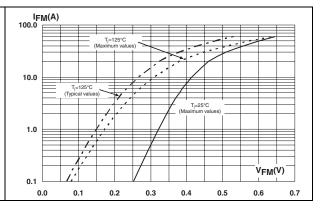
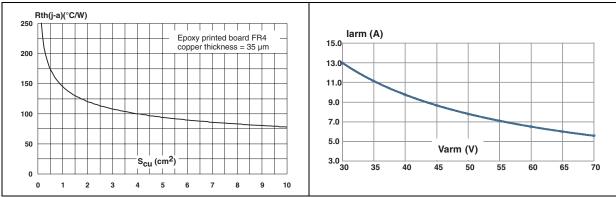


Figure 10. Reverse safe operating area $(t_p < 1 \ \mu s \ and \ T_i < 150 \ ^\circ C)$





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Package information

2 Package information

- Epoxy meets UL94,V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5.PowerFLAT 5x6 dimensions

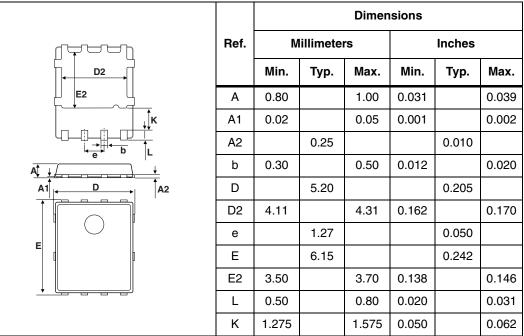
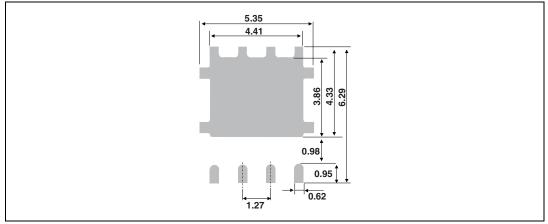
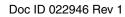


Figure 11. Footprint (dimensions in mm)

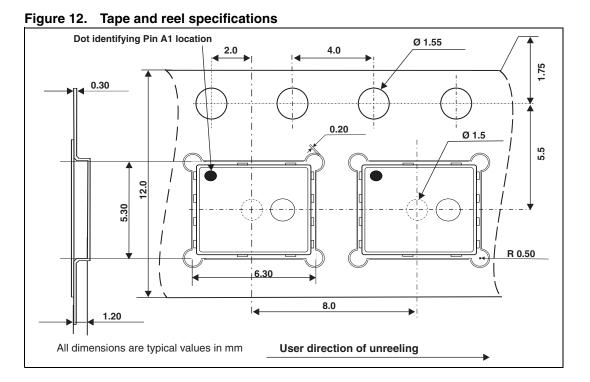






Ordering information

STPS30L30DJF



3 Ordering information

Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30L30DJF-TR	PS30 L30	PowerFLAT 5x6	0.095 g	3000	Tape and reel

4 Revision history

Table 7.	Document revision history
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Date	Revision	Changes
16-Mar-2012	1	First issue.





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